

QUICKSWITCH® PRODUCTS HIGH-SPEED CMOS QUADRUPLE BUS SWITCH WITH INDIVIDUAL ACTIVE LOW ENABLES

QS3125

FEATURES:

- · Enhanced N channel FET with no inherent diode to Vcc
- · Pin compatible with the 74'125 function
- · Zero propagation delay, zero added ground bounce
- · Undershoot clamp diodes on all switch and control inputs
- · Available in QSOP and SOIC packages

APPLICATIONS:

- · Hot-swapping, hot-docking
- · Voltage translation (5V to 3.3V)
- · Power conservation
- Capacitance reduction and isolation (mass storage, work stations)
- · Logic replacement (data processing)
- · Clock gating
- · Bus isolation

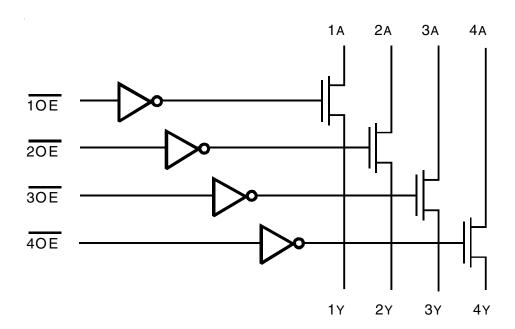
DESCRIPTION:

The QS3125 provides a set of four high-speed low resistance CMOS switches connecting inputs to outputs without propagation delay and without generating additional ground bounce noise. Individual enables (\overline{OE}) are used to turn on the switches. The QS3125 is ideal for signal and control switching since the device adds no noise, ground bounce, propagation delay, or significant power consumption to the system. The QS3125 can also be used for analog switching applications such as video.

QuickSwitch devices provide an order of magnitude faster speed than conventional logic devices.

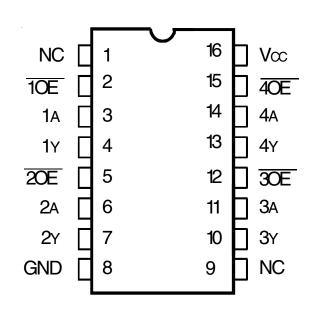
The QS3125 is characterized for operation at -40°C to +85°C.

FUNCTIONAL BLOCK DIAGRAM



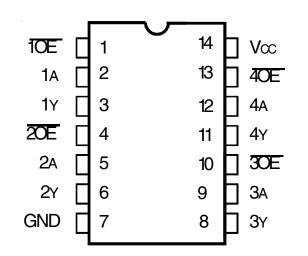
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PIN CONFIGURATION



TOP VIEW

| Package Type | Package Code | Order Code |
|--------------|--------------|------------|
| QSOP | PCG16 | QG |



TOP VIEW

| Package Type | Package Code | Order Code |
|--------------|--------------|------------|
| SOIC | DCG14 | S1G |

ABSOLUTE MAXIMUM RATINGS(1)

| Symbol | Description | Max | Unit |
|----------------------|---------------------------------------|-------------|------|
| VTERM ⁽²⁾ | Supply Voltage to Ground | -0.5 to +7 | V |
| VTERM ⁽³⁾ | DC Switch Voltage Vs | -0.5 to +7 | V |
| VTERM ⁽³⁾ | DC Input Voltage ViN | -0.5 to +7 | V |
| VAC | AC Input Voltage (pulse width ≤20ns) | -3 | V |
| Іоит | DC Output Current | 120 | mA |
| Рмах | Maximum Power Dissipation (TA = 85°C) | 0.5 | W |
| Tstg | Storage Temperature | -65 to +150 | °C |

NOTES:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. All terminals except Vcc .

CAPACITANCE (TA = +25°C, f = 1MHz, VIN = 0V, VOUT = 0V)

| Pins | Тур. | Max. ⁽¹⁾ | Unit |
|-----------------------------------|------|---------------------|------|
| OE (Inputs) | 3 | 5 | pF |
| Quickswitch Channels (Switch OFF) | 5 | 7 | рF |

NOTE:

1. This parameter is guaranteed but not production tested.

PIN DESCRIPTION

| Pin Names | I/O | Description | |
|-----------|-----|-------------------|--|
| 1a - 4a | I/O | Bus A | |
| 1y - 4y | I/O | Bus Y | |
| 10E - 40E | I | Bus Switch Enable | |

FUNCTION TABLE(1)

| хОE | хА | хҮ | Function |
|-----|----|----|------------|
| L | Н | Н | Connect |
| L | L | L | Connect |
| Н | Х | Χ | Disconnect |

NOTE:

- 1. H = HIGH Voltage Level
 - L = LOW Voltage Level
 - X = Don't Care

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

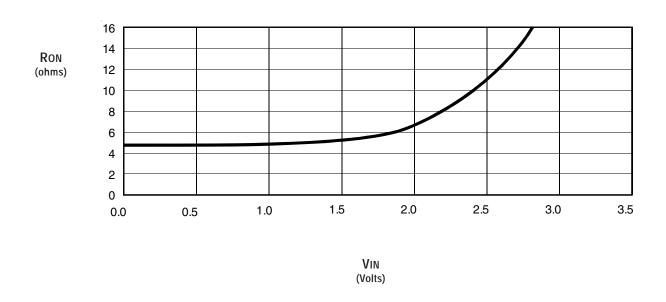
Industrial: TA = -40° C to $+85^{\circ}$ C, VCC = $5V \pm 5\%$

| Symbol | Parameter | Test Conditions | Min. | Typ. ⁽¹⁾ | Max. | Unit |
|--------|--|--|------|---------------------|------|------|
| VIH | Input HIGH Voltage | Guaranteed Logic HIGH for Control Inputs | 2 | _ | _ | V |
| VIL | Input LOW Voltage | Guaranteed Logic LOW for Control Inputs | _ | _ | 0.8 | V |
| lin | Input Leakage Current (Control Inputs) | 0V ≤ Vin ≤ Vcc | _ | _ | ±1 | μΑ |
| loz | Off-State Current (Hi-Z) | 0V ≤ Vouт ≤ Vcc, Switches OFF | _ | _ | ±1 | μΑ |
| Ron | Switch ON Resistance ⁽²⁾ | Vcc = Min., VIN = 0V, ION = 30mA | 1 | 5 | 7 | Ω |
| | | VCC = Min., VIN = 2.4V, ION = 15mA | _ | 10 | 15 | |
| VP | Pass Voltage ⁽³⁾ | $V_{IN} = V_{CC} = 5V$, $I_{OUT} = -5\mu A$ | 3.7 | 4 | 4.2 | V |

NOTES:

- 1. Typical values are at Vcc = 5V and TA = 25°C.
- 2. Ron is guaranteed but not production tested.
- 3. Pass voltage is guaranteed but not production tested.

TYPICAL ON RESISTANCE vs VIN AT VCC = 5V



HIGH-SPEED CMOS QUADRUPLE BUS SWITCH WITH INDIVIDUAL ENABLES

POWER SUPPLY CHARACTERISTICS

| Symbol | Parameter | eter Test Conditions ⁽¹⁾ | | Unit |
|--------|--|---|------|--------|
| Icco | Quiescent Power Supply Current | Vcc = Max., Vin = GND or Vcc, f = 0 | 3 | μA |
| Δlcc | Power Supply Current per Input HIGH(2) | Vcc = Max., Vin = 3.4V, f = 0 | 2.5 | mA |
| ICCD | Dynamic Power Supply Current per MHz (3) | Vcc = Max., A and Y Pins Open, Control Inputs Toggling @ 50% Duty Cycle | 0.25 | mA/MHz |

NOTES:

- 1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- 2. Per TTL-driven input (V_{IN} = 3.4V, control inputs only). A and Y pins do not contribute to ∆lcc.
- 3. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and Y inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

 $T_A = -40^{\circ}C \text{ to } +85^{\circ}C, V_{CC} = 5V \pm 5\%$

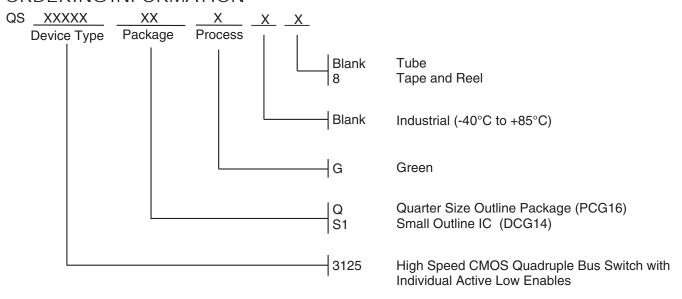
CLOAD = 50pF, RLOAD = 500Ω unless otherwise noted.

| Symbol | Parameter | Min. ⁽¹⁾ | Тур. | Max. | Unit |
|--------------|---------------------------------------|---------------------|------|---------------------|------|
| t PLH | Data Propagation Delay ⁽²⁾ | _ | _ | 0.25 ⁽³⁾ | ns |
| t PHL | A to Y | | | | |
| tpzl | Switch Turn-On Delay | 1.5 | _ | 6.5 | ns |
| tpzh | OE to xA/xY | | | | |
| tplz | Switch Turn-Off Delay ⁽²⁾ | 1.5 | _ | 5.5 | ns |
| tphz | OE to xA/xY | | | | |

NOTES:

- 1. Minimums are guaranteed but not production tested.
- 2. This parameter is guaranteed but not production tested.
- 3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns at C_L = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION



Orderable Part Information

| Speed (ns) | Orderable Part ID | Pkg. Code | Pkg. Type | Temp. Grade |
|---------------|-------------------|--------------|--------------|----------------|
| | QS3125QG | PCG16 | QSOP | I |
| QS3125QG8 | | PCG16 | QSOP | I |
| | QS3125S1G | DCG14 | SOIC | I |
| | QS3125S1G8 | DCG14 | SOIC | Ī |

Datasheet Document History

02/08/2011 Pg. 5 Updated the ordering information by removing the "IDT" notation, non RoHS part and by adding

Tape and Reel information.

05/06/2019 Pg. 2,6 Added table under pin configuration diagram with detailed package information and orderable part information table.

Updated the ordering information diagram in clearer detail.



CORPORATE HEADQUARTERS

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